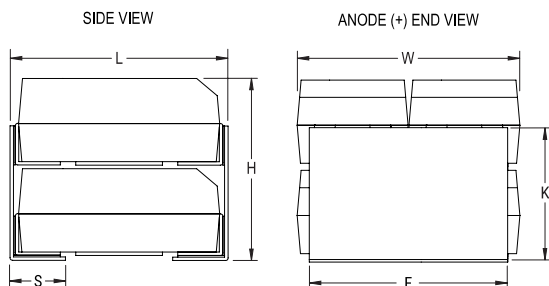


TSM, Tantalum, MnO2 Tantalum, HRA, 1,300 uF, 10%, 10 VDC, 4X



General Information	
Series:	TSM
Dielectric:	MnO2 Tantalum
Style:	Stacked Chip
Description:	SMD, MnO2, Stacks, High Reliability
Features:	High Reliability
RoHS:	Yes
Termination:	Tin
AEC-Q200:	No
MSL:	1

Dimensions	
Case Code	4X
L	8mm +/-0.38mm
W	8.9mm +/-0.2mm
H	8.9mm +/-0.38mm
S	1.9mm +/-0.38mm
F	7.4mm +/-0.2mm
K	6.9mm +/-0.38mm

Specifications	
Capacitance:	1,300 uF
Capacitance Tolerance:	10%
Voltage DC:	10 VDC (85C), 6.7 VDC (125C)
Temperature Range:	-55/+125°C
Rated Temperature:	85°C
Dissipation Factor:	10% 120Hz 25C
Failure Rate:	N/A
Resistance:	0.013 Ohms (100kHz 25C)
Leakage Current:	132 uA (5min 25°C)
Testing and Reliability:	Standard Testing Only

Packaging Specifications	
Packaging:	Tray
Packaging Quantity:	50

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